

AP2608AGK-HF-VB Datasheet

N-Channel 150 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
150	0.283 at V _{GS} = 10 V	3		

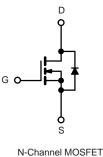
FEATURES

- Trench Power MOSFET
- 175 °C Junction Temperature
- PWM Optimized
- 100 % R_a Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

· Primary Side Switch





ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted) Parameter Symbol Limit Unit **Drain-Source Voltage** V_{DS} 150 V Gate-Source Voltage V_{GS} ± 20 T_C = 25 °C 5 Continuous Drain Current (T_J = 175 °C)^b I_D T_C = 125 °C 4.2 Pulsed Drain Current 10 А I_{DM} Continuous Source Current (Diode Conduction) I_{S} 6 Avalanche Current 6 I_{AS} Single Pulse Avalanche Energy L = 0.1 mH E_{AS} 18 mJ T_C = 25 °C 96^b P_D Maximum Power Dissipation W T_A = 25 °C 3^a T_J, T_{stg} °C Operating Junction and Storage Temperature Range - 55 to 175

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
hunding to Ambient	t ≤ 10 s	R _{thJA}	15	18	°C/W	
Junction-to-Ambient ^a	Steady State		40	50		
Junction-to-Case (Drain)		R _{thJC}	0.85	1.1		

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. See SOA curve for voltage derating.





Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$				V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2		4	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
	I _{DSS}	$V_{DS} = 200 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current		$V_{DS} = 200 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$			50	μA	
		V _{DS} = 200 V, V _{GS} = 0 V, T _J = 175 °C			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	40			А	
	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		0.283			
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}, \text{ T}_{J} = 125 \text{ °C}$		0.320			
Drain-Source On-State Resistance ^b		V _{GS} = 10 V, I _D = 3 A, T _J = 175 °C		0.350		Ω	
		V _{GS} = 6 V, I _D = 3 A		0.292			
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 3 A		35		S	
Dynamic ^a							
Input Capacitance	C _{iss}			1800		pF	
Output Capacitance	Coss	V_{GS} = 0 V, V_{DS} = 25 V, F = 1 MHz		180			
Reverse Transfer Capacitance	C _{rss}			80			
Total Gate Charge ^c	Qg			34	51		
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 100 V, V_{GS} = 10 V, I_{D} = 3 A		8		nC	
Gate-Drain Charge ^c	Q _{gd}			12			
Gate Resistance	R _g		0.5		2.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}			15	25		
Rise Time ^c	t _r	V_{DD} = 100 V, R_L = 5.2 Ω		50	75	ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong 3$ A, V_{GEN} = 10 V, R_g = 2.5 Ω		30	45		
Fall Time ^c	t _f			60	90		
Source-Drain Diode Ratings and Char	acteristics (1	_C = 25 °C)					
Pulsed Current	I _{SM}				5	А	
Diode Forward Voltage ^b	V _{SD}	I _F = 3 A, V _{GS} = 0 V		0.9	1.5	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3 A, dl/dt = 100 A/µs		180	250	ns	

Notes:

a. Guaranteed by design, not subject to production testing.

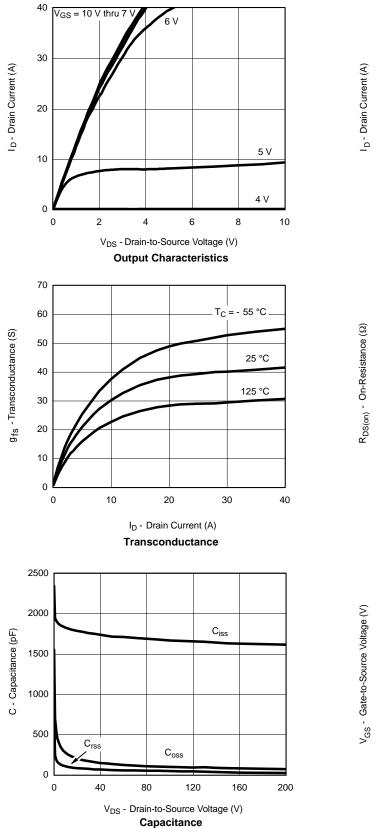
b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

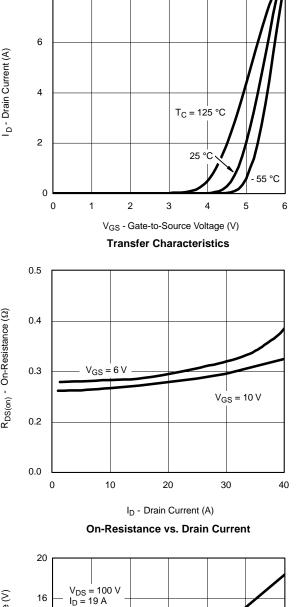
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

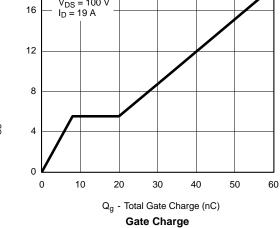








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服务热线:400-655-8788

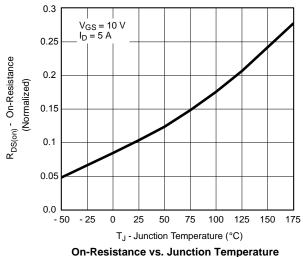


T_J = 25 °C

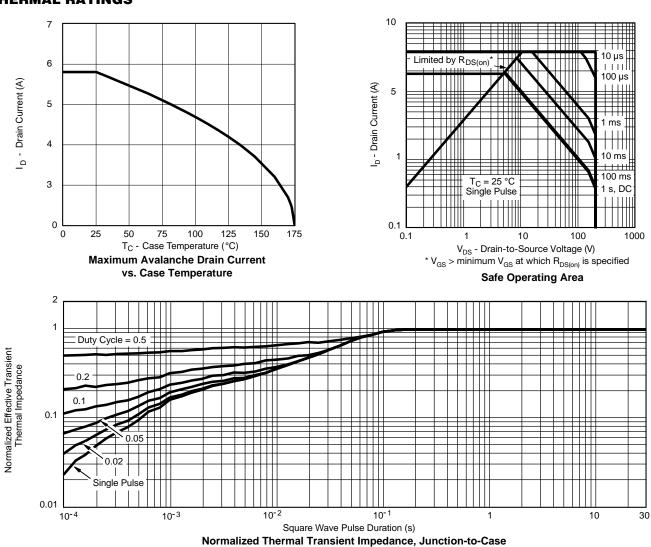
0.9

1.2

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)







100

10

1

0

0.3

T_J = 150 °C

0.6

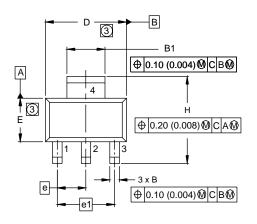
Source-Drain Diode Forward Voltage

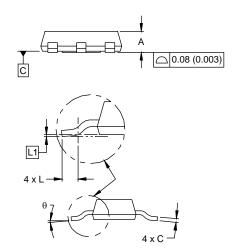
V_{SD} - Source-to-Drain Voltage (V)

I_S - Source Current (A)



SOT-223 (HIGH VOLTAGE)





	MILLIMETERS		INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	1.55	1.80	0.061	0.071	
В	0.65	0.85	0.026	0.033	
B1	2.95	3.15	0.116	0.124	
С	0.25	0.35	0.010	0.014	
D	6.30	6.70	0.248	0.264	
E	3.30	3.70	0.130	0.146	
е	2.30 BSC		0.0905 BSC		
e1	4.60 BSC		0.181 BSC		
Н	6.71	7.29	0.264	0.287	
L	0.91	-	0.036	-	
L1	0.061 BSC		0.0024 BSC		
θ	-	10'	-	10'	
ECN: S-82109-Rev. A, 15-5 DWG: 5969	Sep-08	·	·	<u>.</u>	

Notes

1. Dimensioning and tolerancing per ASME Y14.5M-1994.

2. Dimensions are shown in millimeters (inches).

3. Dimension do not include mold flash.

4. Outline conforms to JEDEC outline TO-261AA.



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